

2SB1417, 2SB1417A

Silicon PNP epitaxial planar type

For power amplification

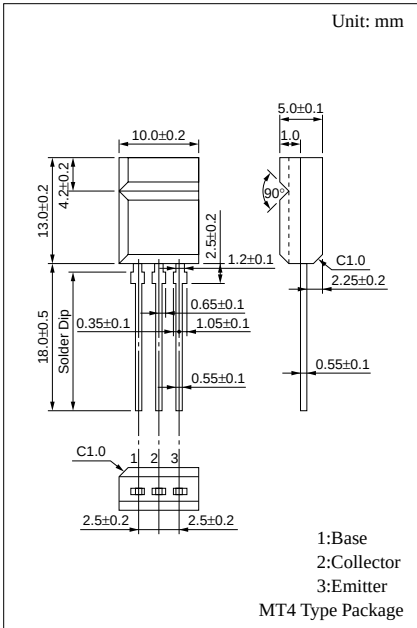
Complementary to 2SD2137 and 2SD2137A

■ Features

- High forward current transfer ratio h_{FE} which has satisfactory linearity
- Low collector to emitter saturation voltage $V_{CE(sat)}$
- Allowing automatic insertion with radial taping

■ Absolute Maximum Ratings ($T_C=25^\circ\text{C}$)

Parameter		Symbol	Ratings	Unit
Collector to base voltage	2SB1417 2SB1417A	V_{CBO}	-60 -80	V
Collector to emitter voltage	2SB1417 2SB1417A		-60 -80	
Emitter to base voltage		V_{EBO}	-6	V
Peak collector current		I_{CP}	-5	A
Collector current		I_C	-3	A
Collector power dissipation	$T_C=25^{\circ}\text{C}$ $T_a=25^{\circ}\text{C}$	P_C	15 2.0	W
Junction temperature			T_j	
Storage temperature		T_{stg}	-55 to +150	$^{\circ}\text{C}$



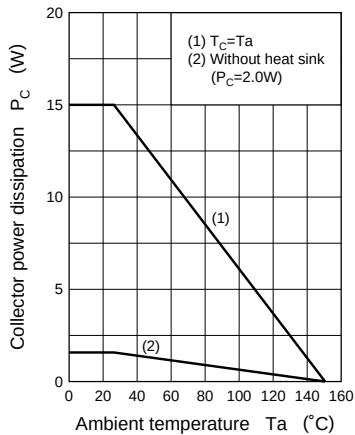
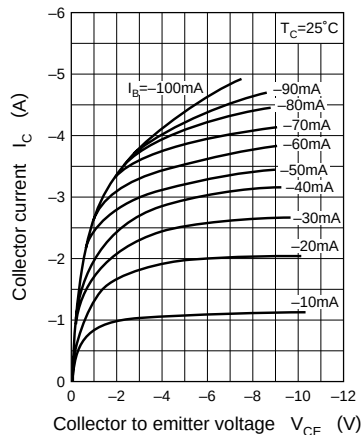
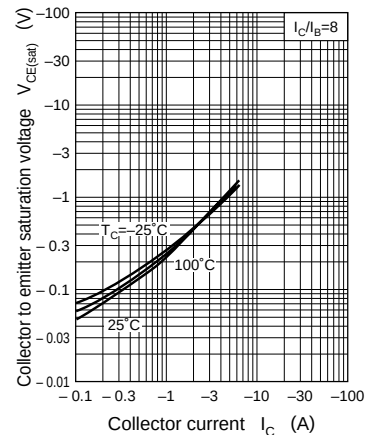
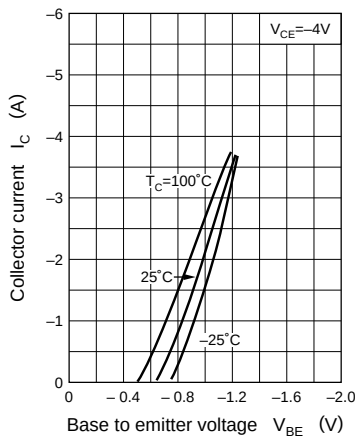
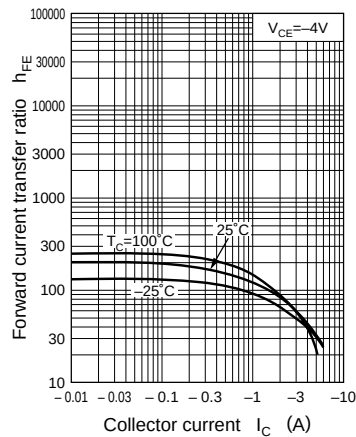
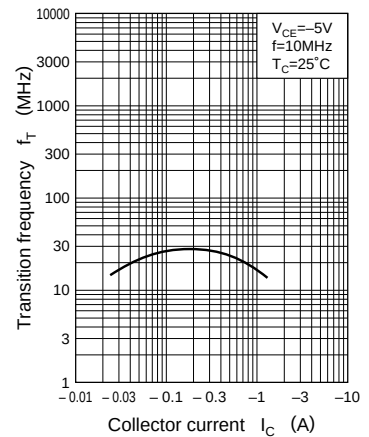
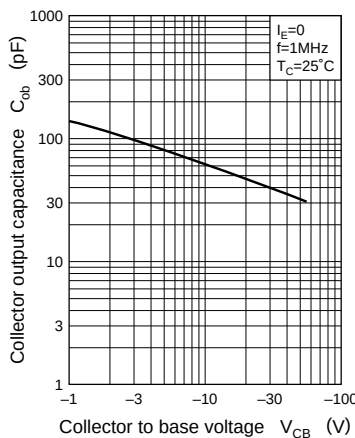
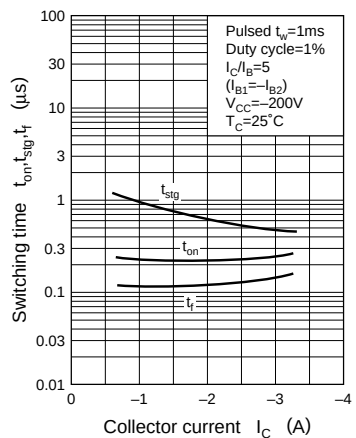
■ Electrical Characteristics ($T_C=25^\circ\text{C}$)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CES}	2SB1417 $V_{CE} = -60\text{V}, V_{BE} = 0$			-100	μA
2SB1417A $V_{CE} = -80\text{V}, V_{BE} = 0$					-100	
Collector cutoff current	I_{CEO}	2SB1417 $V_{CE} = -30\text{V}, I_B = 0$			-100	μA
2SB1417A $V_{CE} = -60\text{V}, I_B = 0$					-100	
Emitter cutoff current	I_{EBO}	$V_{EB} = -6\text{V}, I_C = 0$			-100	μA
Collector to emitter voltage	V_{CEO}	2SB1417 $I_C = -30\text{mA}, I_B = 0$	-60			V
2SB1417A $I_C = -30\text{mA}, I_B = 0$			-80			
Forward current transfer ratio	h_{FE1}^*	$V_{CE} = -4\text{V}, I_C = -1\text{A}$	70		250	
	h_{FE2}	$V_{CE} = -4\text{V}, I_C = -3\text{A}$	10			
Base to emitter voltage	V_{BE}	$V_{CE} = -4\text{V}, I_C = -3\text{A}$			-1.8	V
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = -3\text{A}, I_B = -0.375\text{A}$			-1.2	V
Transition frequency	f_T	$V_{CE} = -5\text{V}, I_C = -0.2\text{A}, f = 10\text{MHz}$		30		MHz
Turn-on time	t_{on}	$I_C = -1\text{A}, I_{B1} = -0.1\text{A}, I_{B2} = 0.1\text{A}, V_{CC} = -50\text{V}$		0.3		μs
Storage time	t_{stg}			1.0		μs
Fall time	t_f			0.2		μs

* h_{FE1} Rank classification

Rank	Q	P
h_{FE1}	70 to 150	120 to 250

Note: Ordering can be made by the common rank (PQ rank $h_{FE1} = 70$ to 250) in the rank classification.

$P_C - T_a$  $I_C - V_{CE}$  $V_{CE(sat)} - I_C$  $I_C - V_{BE}$  $h_{FE} - I_C$  $f_T - I_C$  $C_{ob} - V_{CB}$  $t_{on}, t_{stg}, t_f - I_C$ 

Area of safe operation (ASO)

